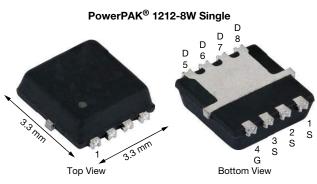
## SQSA84CENW

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**Vishay Siliconix** 

# Automotive N-Channel 80 V (D-S) 175 °C MOSFET



Marking code: Q068

PRODUCT SUMMARY			
V <sub>DS</sub> (V)	80		
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.0320		
$R_{DS(on)} (\Omega)$ at $V_{GS} = 4.5 V$	0.0370		
I <sub>D</sub> (A)	16		
Configuration	Single		

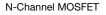
#### **FEATURES**

- TrenchFET<sup>®</sup> power MOSFET
- AEC-Q101 qualified
- 100 % R<sub>q</sub> and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

GC



COMPLIANT HALOGEN FREE



ORDERING INFORMATION	
Package	PowerPAK 1212-8W
Lead (Pb)-free and halogen-free	SQSA84CENW

ABSOLUTE MAXIMUM RATING	<b>S</b> (T <sub>C</sub> = 25 °C, unless	otherwise notec	)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V <sub>DS</sub>	80	V	
Gate-source voltage		V <sub>GS</sub>	± 20	V	
Continuous drain current	T <sub>C</sub> = 25 °C ª	1	16		
Continuous drain current	T <sub>C</sub> = 125 °C	Ι <sub>D</sub>	11		
Continuous source current (diode conductio	n) <sup>a</sup>	I <sub>S</sub>	16	А	
Pulsed drain current <sup>b</sup>		I <sub>DM</sub>	54		
Single pulse avalanche current L = 0.1 mH		I <sub>AS</sub>	14		
Single pulse avalanche energy		E <sub>AS</sub>	9.8	mJ	
Maximum power dissipation	T <sub>C</sub> = 25 °C	D	27	W	
Maximum power dissipation	T <sub>C</sub> = 125 °C	P <sub>D</sub>	9	vv	
Operating junction and storage temperature	range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C	
Soldering recommendations (peak temperature) <sup>d, e</sup>			260	U	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	tion-to-ambient PCB mount <sup>c</sup>		81	°C/W
Junction-to-case (drain)		R <sub>thJC</sub>	5.5	0/10

#### Notes

a. Package limited

b. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 % c. When mounted on 1" square PCB (FR4 material)

See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK1212-8W package may have visible exposed Cu at the end of the lead terminals due to the singulation process. However, the leads also have plated indents on the top and bottom surfaces that promote the d. formation of a solder filet compatible with automated optical inspection methods

e. Rework conditions: manual soldering with a soldering iron is not recommended

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SQSA84CENW

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static							•	
Drain-source breakdown voltage	V <sub>DS</sub>	$V_{GS} = 0, I_D = 250 \ \mu A$		80	-	-	Ň	
Gate-source threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	- V <sub>GS</sub> , I <sub>D</sub> = 250 μA	1.5	2.0	2.5	V	
Gate-source leakage	I <sub>GSS</sub>	V <sub>DS</sub> =	0 V, $V_{GS} = \pm 20 V$	-	-	± 100	nA	
		$V_{GS} = 0 V$	V <sub>DS</sub> = 80 V	-	-	1		
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = 80 V, T <sub>J</sub> = 125 °C	-	-	50	μA	
		V <sub>GS</sub> = 0 V	$V_{DS} = 80 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	150		
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	10	-	-	А	
		V <sub>GS</sub> = 10 V	I <sub>D</sub> = 3.5 A	-	0.0227	0.0320		
	-	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 3.5 A, T <sub>J</sub> = 125 °C	-	-	0.0570		
Drain-source on-state resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 3.5 A, T <sub>J</sub> = 175 °C	-	-	0.0730	Ω	
		$V_{GS} = 4.5 V$	I <sub>D</sub> = 3 A	-	0.0263	0.0370		
Forward transconductance b	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 3.5 A		-	20	-	S	
Dynamic <sup>b</sup>								
Input capacitance	C <sub>iss</sub>		V <sub>DS</sub> = 25 V, f = 1 MHz	-	743	1050	pF	
Output capacitance	Coss	$V_{GS} = 0 V$		-	111	160		
Reverse transfer capacitance	C <sub>rss</sub>			-	8	12		
Total gate charge <sup>c</sup>	Qg			-	14.1	22	nC	
Gate-source charge <sup>c</sup>	Q <sub>gs</sub>	$V_{GS} = 10 V$	$V_{DS} = 40 \text{ V}, \text{ I}_{D} = 5 \text{ A}$	-	2.6	-		
Gate-drain charge <sup>c</sup>	Q <sub>gd</sub>			-	2.6	-		
Gate resistance	R <sub>g</sub>		f = 1 MHz	0.35	0.72	1.20	Ω	
Turn-on delay time <sup>c</sup>	t <sub>d(on)</sub>			-	7	12	1	
Rise time <sup>c</sup>	t <sub>r</sub>	- V <sub>DD</sub> =	= 40 V, $R_{L}$ = 10 $\Omega$	-	3	6	1	
Turn-off delay time <sup>c</sup>	t <sub>d(off)</sub>	$I_D \cong 4 \text{ A}, V_{GEN} = 10 \text{ V}, \text{ R}_g = 1 \Omega$		-	15	25	- ns	
Fall time <sup>c</sup>	t <sub>f</sub>			-	3	6		
Source-Drain Diode Ratings and Charact	eristic <sup>b</sup>	1			1		<u></u>	
Pulsed current <sup>a</sup>	I <sub>SM</sub>			-	-	54	Α	
Forward voltage	V <sub>SD</sub>	I <sub>F</sub> =	3.5 A, V <sub>GS</sub> = 0 V	-	0.8	1.1	V	
Body diode reverse recovery time	t <sub>rr</sub>	_		-	27	54	ns	
Body diode reverse recovery charge	Q <sub>rr</sub>			-	23	46	nC	
Reverse recovery fall time	t <sub>a</sub>	I <sub>F</sub> = 5 /	A, di/dt = 100 A/μs	-	19	-		
Reverse recovery rise time	t <sub>b</sub>	1		-	8	-	ns	
Body diode peak reverse recovery current	I <sub>RM(REC)</sub>	1		-	-1.39	-	А	

Notes

a. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%$ 

b. Guaranteed by design, not subject to production testing

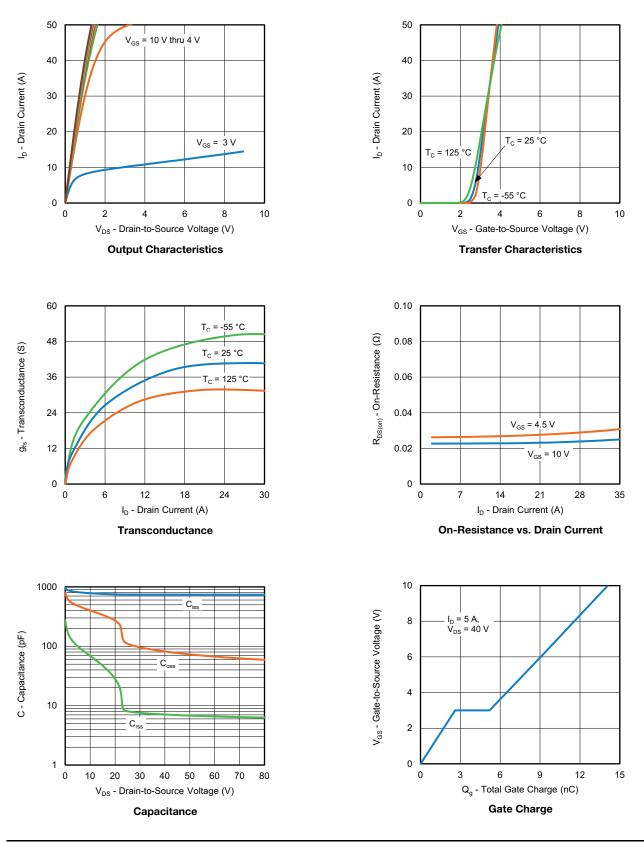
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2



### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



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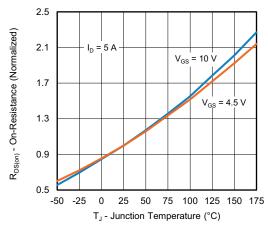
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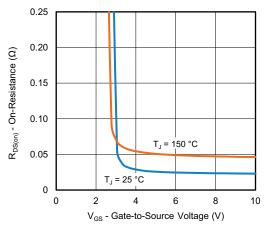
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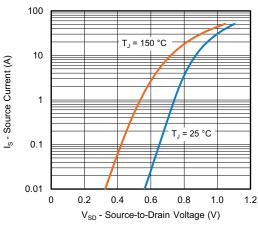
## **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



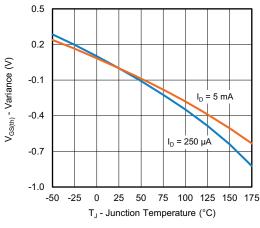
**On-Resistance vs. Junction Temperature** 



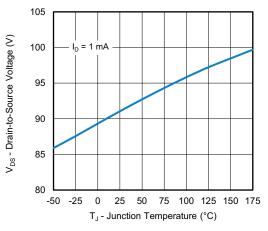
On-Resistance vs. Gate-to-Source Voltage



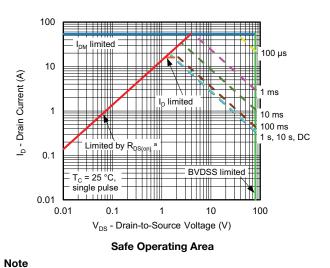
Source Drain Diode Forward Voltage



Threshold Voltage



Drain Source Breakdown vs. Junction Temperature



a.  $V_{GS}$  > minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified

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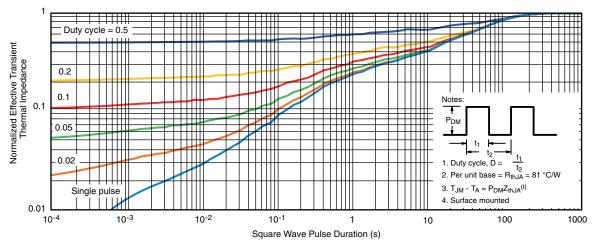
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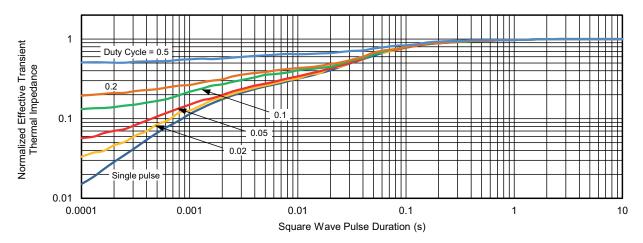




#### THERMAL RATINGS (T<sub>A</sub> = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

#### Note

The characteristics shown in the two graphs

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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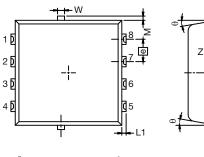
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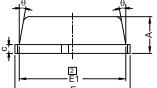


# PowerPAK<sup>®</sup> 1212-8W Case Outline

Δ2

224





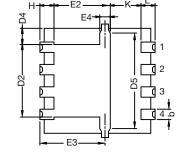


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Detail Z



Backside view of single pad

Notes
1 Inch will govern

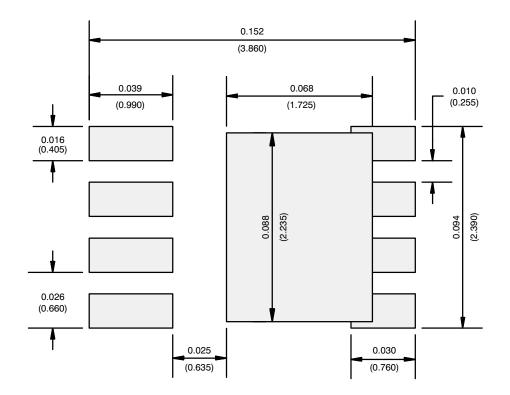
 Dimensions exclusive of mold gate burrs
 Dimensions exclusive of mold flash and cutting burrs

DIM	MILLIMETERS			INCHES		
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
А	0.97	1.04	1.12	0.038	0.041	0.044
A1	0	-	0.05	0	-	0.002
A2	0	-	0.13	0	-	0.005
b	0.23	0.30	0.41	0.009	0.012	0.016
С	0.23	0.28	0.33	0.009	0.011	0.013
D	3.20	3.30	3.40	0.126	0.130	0.134
D1	2.95	3.05	3.15	0.116	0.120	0.124
D2	1.98	2.11	2.24	0.078	0.083	0.088
D4		0.47 typ. 0.0185 typ.				
D5	2.3 typ.			0.090 typ.		
E	3.20	3.30	3.40	0.126	0.130	0.134
E1	2.95	3.05	3.15	0.116	0.120	0.124
E2	1.47	1.60	1.73	0.058	0.063	0.068
E3	1.75	1.85	1.98	0.069	0.073	0.078
E4		0.34 typ.			0.013 typ.	
е		0.65 BSC.		0.026 BSC		
К	K 0.86 typ.		0.034 typ.			
Н	0.30	0.41	0.51	0.012	0.016	0.020
L	0.30	0.43	0.56	0.012	0.017	0.022
L1	0.06	0.13	0.20	0.002	0.005	0.008
θ	0°	-	12°	0°	-	12°
W	0.15	0.25	0.36	0.006	0.010	0.014
М	0.125 typ.			0.125 typ. 0.005 typ.		

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## RECOMMENDED MINIMUM PADS FOR PowerPAK<sup>®</sup> 1212-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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